TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7MH161FK,TC7MH163FK

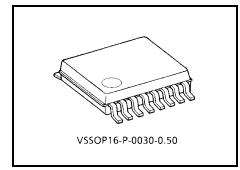
Synchronous Presettable 4-Bit Binary Counter TC7MH161FK Asynchronous Clear TC7MH163FK Synchronous Clear

The TC7MH161FK and 163FK are advanced high speed CMOS synchronous presettable 4-bit binary counters fabricated with silicon gate  $\rm C^2MOS$  technology.

They achieve the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

The CK input is active on the rising edge. Both  $\overline{\text{LOAD}}$  and  $\overline{\text{CLR}}$  inputs are active on low logic level.

Presetting of each IC's is synchronous to the rising edge of CK. The clear function of the TC7MH163FK is synchronous to CK, while the TC7MH161FK are cleared asynchronously.



Weight: 0.02 g (typ.)

Two enable inputs (ENP and ENT) and CARRY OUTPUT are provided to enable easy cascading of counters, which facilitates easy implementation of n-bit counters without using external gates.

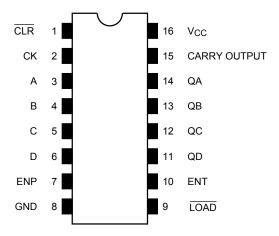
An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### **Features**

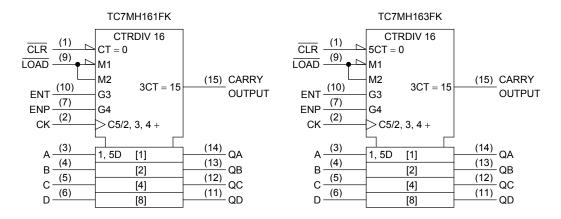
- High speed:  $f_{max} = 185 \text{ MHz}$  (typ.) (V<sub>CC</sub> = 5 V)
- Low power dissipation:  $I_{CC} = 4 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- · Power down protection is equipped with all inputs.
- $\bullet \quad \text{Balanced propagation delays: } t_{pLH} \approx t_{pHL}$
- Wide operating voltage range:  $V_{CC \text{ (opr)}} = 2 \sim 5.5 \text{ V}$
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS161/163

1 2007-10-19

### Pin Assignment (top view)



### **IEC Logic Symbol**



#### **Truth Table**

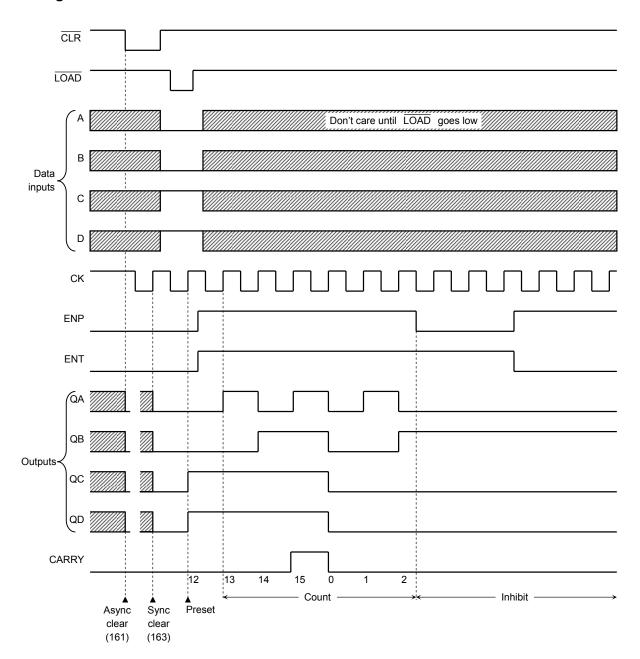
TC7MH161FK				TC7MH163FK				Outputs								
		Inputs					Inputs			Outputs				Function		
CLR	LD	ENP	ENT	CK	CLR	LD	ENP	ENT	CK	QA	QB	QC	QD			
L	Х	Х	Х	Х	L	Х	Х	Х		L L L L			L	Reset to "0"		
Н	L	Х	Х	$\Box$	Н	L	Х	Х	$\Box$	Α	В	С	D	Reset data。		
Н	Н	Х	L		Н	Н	Х	L		No change				No count		
Н	Н	L	Х		Н	Н	L	Х		No change				No count		
Н	Н	Н	Н		Н	Н	Н	Н		Count up			•	Count		
Н	Х	Х	Х	$\neg$	Х	Х	Х	Х	$\neg$	No change				No count		

X: Don't care

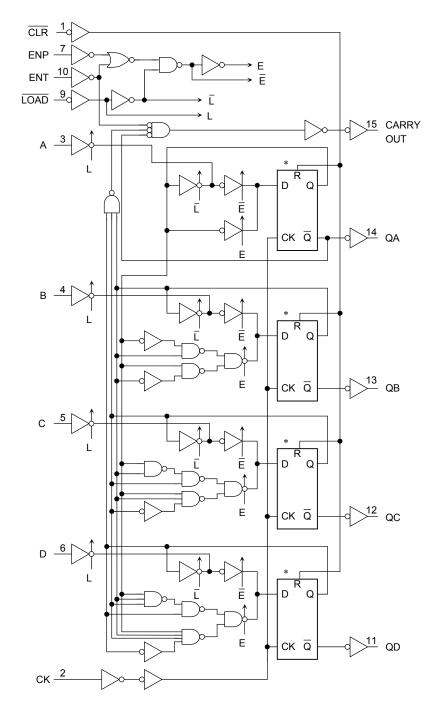
A, B, C, D: Logic level of data inputs

Carry:  $CARRY = ENT \cdot QA \cdot QB \cdot QC \cdot QD$ 

# **Timing Chart**



# **System Diagram**



\*:Truth table of internal F/F

1		TC	7MH16	151/		TC7MH163FK						
		10	IVIT IO	IFN			10	IVITIO	OFK			
	D	CK	R	Q	Q	D	CK	R	Q	Q		
	Х	Х	Н	L	Н	Х		Н	L	Н		
	L		L	L	Н	L		L	L	Н		
	Н	Ļ	L	Ι	L	Ι	Ļ	L	Ι	L		
	X	$\neg$	L	No ch	nange	Х	$\neg$	Х	No ch	nange		

X: Don't care

4 2007-10-19



## **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5~7.0	V
DC input voltage	VIN	-0.5~7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5	V
Input diode current	lıĸ	-20	mA
Output diode current	Іок	±20	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T <sub>stg</sub>	-65~150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	2.0~5.5	V	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	Vout	0~V <sub>CC</sub>	V	
Operating temperature	T <sub>opr</sub>	-40~85	°C	
Input rise and fall time	dt/dv	$0\sim100~(V_{CC}=3.3\pm0.3~V)$	ns/V	
input rise and fail time	dilav	$0\sim20 \ (V_{CC}=5\pm0.5 \ V)$		

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics		Symbol	Test Condition				Га = 25°C		Ta = -4	0~85°C	Linit											
Cilarat	Clensucs	Syllibol			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic											
						1.50	_	_	1.50	_												
Input voltage	High level	V <sub>IH</sub>		_	3.0~5.5	V <sub>CC</sub> × 0.7	_	_	V <sub>CC</sub> × 0.7		V ( ) ( ) ( ) ( ) ( ) ( ) ( ) ( ) ( ) (											
input voltage					2.0	_		0.50	_	Max	v											
	Low level	VIL		_	3.0~5.5	_		V <sub>CC</sub> × 0.3		V <sub>CC</sub> × 0.3												
							., .,		2.0	1.9	2.0	-	1.9	-								
			V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	., .,	., .,	., .,		., .,	., .,	., .,	., .,	., .,	., .,	., .,	., .,	$I_{OH} = -50 \mu A$	3.0	2.9	3.0	_	2.9	1.50 — VCC × 0.7 — 0.50 — VCC × 0.3 1.9 — 2.9 — 4.4 — 2.48 — 3.80 — V — 0.1 — 0.1 — 0.1 — 0.1 — 0.44 — 0.44 — 1.0 μΑ
	High level	VoH			4.5	4.4	4.5	_	4.4	Min Max  .50 —  .50 —  .50 —  .50 —  .50 —  .50 —  .50 —  .50 —  .50 —  .50 —  .50 —  .50 —  .50 —  .4.4 —  .4.4 —  .4.4 —  .4.4 —  .4.4 —  .4.4 —  .5.5 —  .6.1 —  .7	İ											
			- 12	$I_{OH} = -4 \text{ mA}$	3.0	2.58		_	2.48													
Output				$I_{OH} = -8 \text{ mA}$	4.5	3.94	ı	-	3.80	-	\/											
voltage					2.0	_	0	0.1	_		ľ											
				$I_{OL} = 50 \mu A$	3.0	_	0	0.1	_	0.1												
	Low level	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$		4.5	_	0	0.1	_	0.1												
			- 12	$I_{OL} = 4 \text{ mA}$	3.0	_		0.36		0.44												
				I <sub>OL</sub> = 8 mA	4.5	_		0.36	_	0.44												
Input leakage	current	I <sub>IN</sub>	$V_{IN} = 5.5$	v or GND	0~5.5	_		±0.1	_	±1.0	μА											
Quiescent sup	ply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$	or GND	5.5	_		4.0		40.0	μΑ											



# Timing Requirements (Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	mbol Test Condition			Ta = 25°C	Ta = -40~85°C	Unit	
Characteristics	Official Contract		OII	V <sub>CC</sub> (V)	Limit	Limit	Offic	
Minimum pulse width	t <sub>w (H)</sub>	Figure 1		$3.3\pm0.3$	5.0	5.0	ns	
(CK)	t <sub>w (L)</sub>	i iguie i	1		5.0	5.0	115	
Minimum pulse width	+ 41	Figure 4	(Note 1)	$3.3 \pm 0.3$	5.0	5.0		
(CLR)	t <sub>w (L)</sub>	rigule 4	(Note 1)		5.0	5.0	ns	
Minimum set-up time		Figure 2		$3.3 \pm 0.3$	5.5	6.5	ns	
(A, B, C, D)	ts	rigure 2		5.0 ± 0.5	4.5	4.5	115	
Minimum set-up time	1			$3.3\pm0.3$	8.0	9.5	ns	
( <del>LOAD</del> )	ts	Figure 2			5.0	6.0	115	
Minimum set-up time	1	Figure 2		$3.3\pm0.3$	7.5	9.0	ns	
(ENT, ENP)	ts	Figure 3		5.0 ± 0.5	5.0	6.0	115	
Minimum set-up time		Figure F	(Note 2)	$3.3\pm0.3$	4.0	4.0	no	
(CLR)	ts	Figure 5	(Note 2)	5.0 ± 0.5	3.5	3.5	ns	
Minimum hold time	4.	Figure 2 Figure 2		$3.3\pm0.3$	1.0	1.0	no	
Willimum noid time	t <sub>h</sub>	rigule 2, rigule 3	Figure 2, Figure 3			1.0	ns	
Minimum hold time	1	Figure F	(Note 2)	$3.3\pm0.3$	1.0	1.0		
(CLR)	t <sub>h</sub>	Figure 5	(Note 2)		1.5	1.5	ns	
Minimum removal time		Figure 4	(Note 4)	$3.3 \pm 0.3$	2.5	2.5		
(CLR)	t <sub>rem</sub>	Figure 4	(Note 1)	5.0 ± 0.5	1.5	1.5	ns	

Note 1: for TC7MH161FK only Note 2: for TC7MH163FK only



## AC Characteristics (Input: $t_r = t_f = 3$ ns)

		T 10 III			-	Га = 25°C		Ta = -4	0~85°C		
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Min	Max	Unit	
			3.3 ± 0.3	15	_	8.3	12.8	1.0	15.0		
Propagation delay time	t <sub>pLH</sub>	Figure 4 Figure 2	3.3 ± 0.3	50	_	10.8	16.3	1.0	18.5		
(CK-Q)	tpHL	Figure 1, Figure 2	50.05	15	_	4.9	8.1	1.0	9.5	ns	
			$5.0 \pm 0.5$	50	_	6.4	10.1	1.0	11.5		
Dan and date there			3.3 ± 0.3	15	_	8.7	13.6	1.0	16.0		
Propagation delay time	t <sub>pLH</sub>	Figure 1	3.3 ± 0.3	50	_	11.2	17.1	1.0	19.5	no	
(CK-CARRY) [Count mode]	tpHL	rigure i	50.05	15	_	4.9	8.1	1.0	9.5	115	
[Count mode]			5.0 ± 0.5	50	_	6.4	10.1	1.0	11.5		
Dranagation dalay time			3.3 ± 0.3	15	_	11.0	17.2	1.0	20.0		
Propagation delay time (CK-CARRY)	t <sub>pLH</sub>	Figure 2	3.3 ± 0.3	50	_	13.5	20.7	1.0	23.5	ne	
[Preset mode]	t <sub>pHL</sub>	rigure 2	5.0 ± 0.5	15	_	6.2	10.3	1.0	12.0	115	
[i reset mode]			3.0 ± 0.3	50	_	7.7	12.3	1.0	14.0		
	t <sub>pLH</sub>	Figure 6	3.3 ± 0.3	15	_	7.5	12.3	1.0	14.5	ns	
Propagation delay time				50	_	10.5	15.8	1.0	18.0		
(ENT-CARRY)	tpHL	i iguic o	5.0 ± 0.5	15	_	4.9	8.1	2.8	113		
				3.0 ± 0.5	50	_	6.4	10.1	1.0	11.5	
			3.3 ± 0.3	15	_	8.9	13.6	1.0	16.0		
Propagation delay time	taru	Figure 4 (Note 2)		50	_	11.2	17.1	1.0	19.5	ns	
(CLR -Q)	t <sub>pHL</sub>	riguic + (Note 2)		15	_	5.5	9.0	1.0	10.5	ns	
			5.0 ± 0.5	50	_	7.0	11.0	1.0	12.5		
			3.3 ± 0.3	15	_	8.4	13.2	1.0	15.5		
Propagation delay time	t <sub>pHL</sub>	Figure 4 (Note 2)		50	_	10.9	16.7	1.0	19.0	ns	
(CLR -CARRY)	фпь		5.0 ± 0.5	15	_	5.0	8.6	1.0	10.0	110	
			0.0 ± 0.0	50	_	6.5	10.6	1.0	12.0		
			3.3 ± 0.3	15	80	130	_	70	_		
Maximum clock frequency	fmax	_	3.0 ± 0.0	50	55	85	_	50	_	MHz	
Maximum clock frequency	f <sub>max</sub>		5.0 ± 0.5	15	135	185	_	115	_	IVIMZ	
			3.0 ± 0.0	50	95	125	_	85	_		
Input capacitance	C <sub>IN</sub>	-	_		_	4	10	_	10	pF	
Power dissipation capacitance	C <sub>PD</sub>			(Note 1)	_	23		_	_	pF	

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

When the outputs drive a capacitive load, total current consumption is the sum of  $C_{PD}$ , and  $\Delta I_{CC}$  which is obtained from the following formula:

$$\Delta I_{CC} = f_{CK} \cdot V_{CC} \left( \frac{C_{QA}}{2} + \frac{C_{QB}}{4} + \frac{C_{QC}}{8} + \frac{C_{QD}}{16} + \frac{C_{CO}}{16} \right)$$

 $C_{QA}\sim C_{QD}$  and  $C_{CO}$  are the capacitance QA $\sim$ QD and CARRY OUT, respectively.  $f_{CK}$  is the input frequency of the CK.

Note 2: for TC7MH161FK only

### **AC Test Waveform**

### **Count Mode**

#### 

Figure 1

### **Preset Mode**

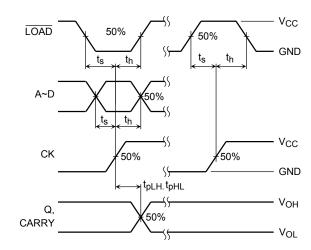


Figure 2

#### **Count Enable Mode**

# Clear Mode (TC7MH161FK)

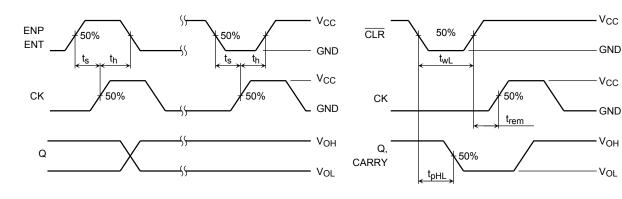


Figure 3 Figure 4

# Clear Mode (TC7MH163FK)

#### 

Figure 5

# **Cascade Mode (fix maximum count)**

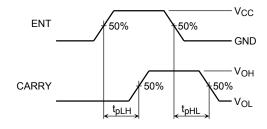
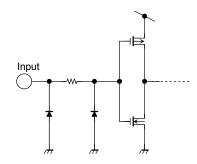


Figure 6

# Noise Characteristics (Input: $t_r = t_f = 3$ ns)

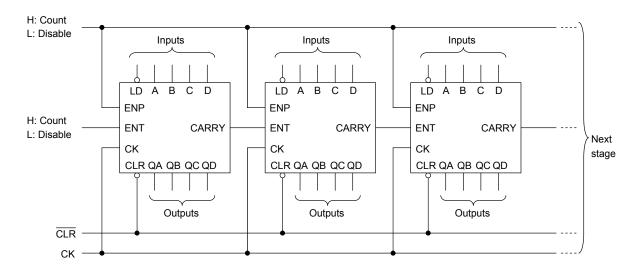
Characteristics	Symbol	Test Condition		Ta =	Unit	
Characteristics	Symbol	rest condition	V <sub>CC</sub> (V)	Тур.	Limit	Offic
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.4	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.4	-0.8	V
Minimum high level dynamic input voltage $V_{\text{IH}}$	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage $V_{\text{IL}}$	V <sub>ILD</sub>	$C_L = 50 \text{ pF}$	5.0		1.5	٧

# **Input Equivalent Circuit**

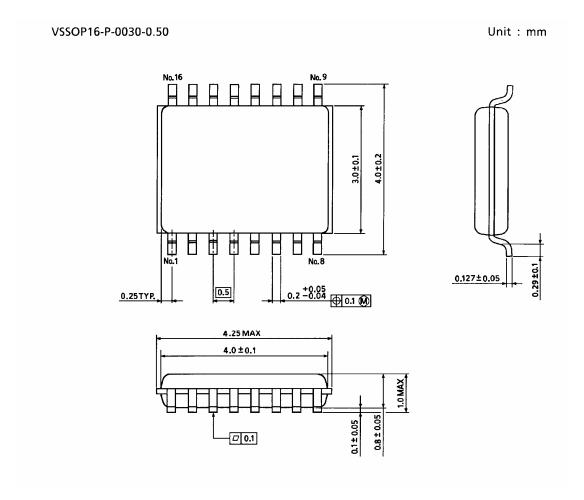


# **Typical Application**

# **Parallel Carry N-Bit Counter**



# **Package Dimensions**



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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